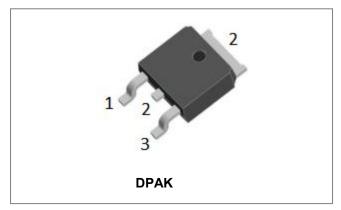


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Technical Data Data Sheet N1566, Rev. A



20CWQ10FN SCHOTTKY RECTIFIER



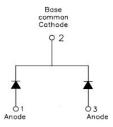
Features

- 175°C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
 High frequency operation
- High frequency operation
 Guard ring for ophanced rugger
- Guard ring for enhanced ruggedness and long term reliability
- "-A" is an AEC-Q101 qualified device
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Disk drives
- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Battery charging

Circuit Diagram



Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	200	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle $@T_c = 159^{\circ}C$, rectangular wave form	10(peg leg) 20(peg device)	A
Peak One Cycle Non-Repetitive Surge Current(peg leg)	I _{FSM}	8.3 ms, half Sine pulse	100	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop	V _{F1}	@ 10A, Pulse, T _J = 25 °C	0.80	0.85	V
(per leg) *	V _{F2}	@ 10A, Pulse, T _J = 125 °C	0.70	0.75	V
Reverse Current (per leg) *	I _{R1}	@V _R = rated V _R , T _J = 25 °C	0.02	1.0	mA
	I _{R2}	$@V_R$ = rated $V_{R_j}T_J$ = 125 °C	0.4	6.0	mA
Junction Capacitance (per leg)	Ст	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	180	250	pF

* Pulse width < 300 µs, duty cycle < 2%

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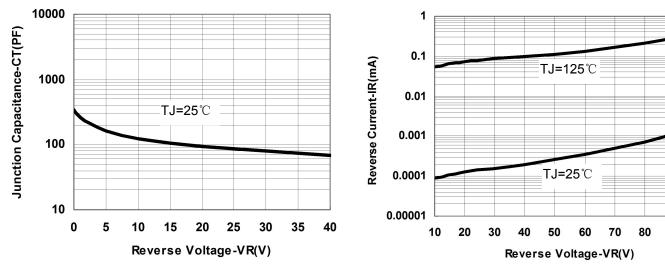
RoHS

Technical Data Data Sheet N1566, Rev. A

Thermal-Mechanical Specifications:

Ratings and Characteristics Curves

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +175	°C
Storage Temperature	T _{stg}	-	-55 to +175	°C
Typical Thermal Resistance Junction to Case	R _{0JC}	-	3.5	°C/W
Approximate Weight	wt	-	0.39	g
Case Style	DPAK			

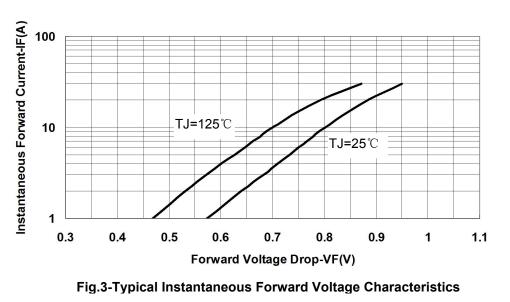






90

100



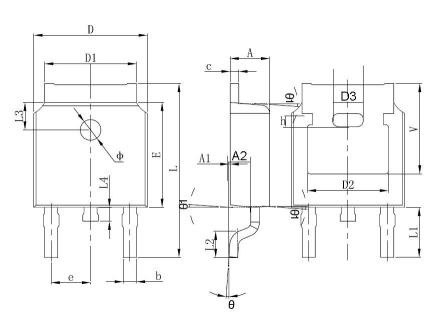
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Technical Data Data Sheet N1566, Rev. A **Mechanical Dimensions DPAK**



CYMDOL	Millimeters		Inc	ches		
SYMBOL	Min.	Max.	Min.	Max.		
A	2.20	2.40	0.087	0.094		
A1	0.00	0.127	0.000	0.005		
b	0.66	0.86	0.026	0.034		
с	0.46	0.60	0.018	0.024		
D	6.50	6.70	0.256	0.264		
D1	5.13	5.46	0.202	0.215		
D2	4.83 REF.		0.190 REF.			
E	6.00	6.20	0.236	0.244		
е	2.186	2.386	0.086	0.094		
L	9.70	10.40	0.381	0.409		
L1	2.90 REF.		0.144 REF.			
L2	1.40	1.70	0.055	0.067		
L3	1.60 REF.		0.063 REF.			
L4	0.60	1.00	0.024	0.039		
Φ	1.10	1.30	0.043	0.051		
Θ	0°	8°	0°	8°		
h	0.00	0.30	0.000	0.012		
V	5.35 REF.		0.211 REF.			

20

Q 10

FN

YΥ

L

ww

SSG

CW

Ordering Information

Device	Package	Shipping
20CWQ10FN	DPAK (Pb-Free)	2500pcs / reel
20CWQ10FNTR	DPAK (Pb-Free)	2500pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel Packaging specification.

Marking Diagram



Where XXXXX is YYWWL

= Forward Current (20A)

= Configuration

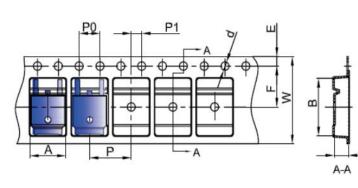
- = Configuration = Device Type = Reverse Voltage (100V) = Package type
- = SSG

= Year

= Week = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Carrier Tape Specification DPAK



SYMBOL	Millimeters		
	Min.	Max.	
A	6.80	7.00	
В	10.40	10.60	
С	2.60	2.80	
d	Φ1.45	Φ1.65	
E	1.65	1.85	
F	7.40	7.60	
P0	3.90	4.10	
Р	7.90	8.10	
P1	1.90	2.10	
W	15.90	16.30	

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